

HW #12: Band Structure

1. – *Density of states for ELECTRONS in 2D solids:*

Hofmann Ch 6 walks you through calculating the density of states for a free electron gas in a 3D solid, ending up on page 97 with Equation 6.13:

$$g(E) = \frac{dN}{dE} = \left[\frac{V}{2\pi^2} \left(\frac{2m_e}{\hbar^2} \right)^{3/2} \right] E^{1/2}$$

- A) Following a similar procedure, show that the density of states for a free electron gas in a 2D solid is independent of the energy.
- B) How would the density of states depend on the energy if the electron dispersion were *linear* instead of *quadratic*? (That is, if $E(k) \propto k$ instead of $E(k) \propto k^2$)? — Discuss this for both the 3D and for the 2D cases.

2. – *Band picture of ELECTRONS in solids: (Metals vs. Non-metals)*

Consider a 1D chain of N atoms with one atom per unit cell. Assume periodic boundary conditions and that each atom has Z valence electrons.

- A) Show that you can fill exactly $Z/2$ bands with these electrons or, equivalently, that each band can accommodate $2N$ electrons.
- B) On page 118, the pejorative term “spaghetti diagram” can be used to describe Figure 6.13. Still, it does show that silicon (Si) has four filled bands (for some values of \mathbf{k} , the energies of the bands are degenerate, but not for all). There are also four electrons per Si atom (not eight!). Explain why this is so.
- C) Having an even number of electrons per unit is *necessary but not sufficient* for a solid to be an insulator/semiconductor. Give an example of an elemental solid that is a metal despite having an even number of electrons per unit cell.